Revision. 3

MOS FET

### MTM981400BBF

## **Panasonic**

## MTM981400BBF

### Silicon P-channel MOSFET

### For switching

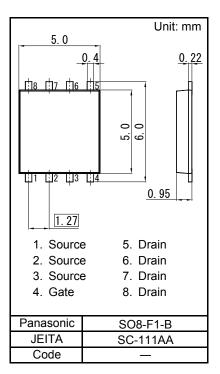
#### ■ Features

- Low drain-source On-state Resistance RDS(on) typ =  $28 \text{ m}\Omega$  (VGS = -4.5 V)
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)

### ■ Marking Symbol BA

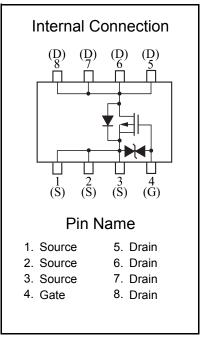
#### ■ Packaging

Embossed type (Thermo-compression sealing) 3 000 pcs / reel (standard)



Parameter	Symbol	Rating	Unit
Drain-source Voltage	VDS	-40	V
Gate-source Voltage	VGS	±20	V
Drain Current	ID	-7.0	Α
Drain Current (Pulsed)	IDp	-28	Α
Total Power dissipation *1	PD	2	W
Channel Temperature	Tch	150	°C
Operating Ambient Temperature	Topr	-40 to +85	°C
Storage Temperature Range	Tstg	-55 to +150	°C

Note: \*1 Measuring on ceramic board at 50 mm  $\times$  50 mm  $\times$  1.0 mm.



Doc No. TT4-EA-10096 Revision. 3

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### ■ Electrical Characteristics Ta = 25°C ± 3°C

**Static Characteristics** 

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Drain-source Breakdown Voltage	VDSS	ID = -1 mA, VGS = 0 V	-40			V
Zero Gate Voltage Drain Current	IDSS	VDS = -40 V, VGS = 0 V			-10	μΑ
Gate-source Leakage Current	IGSS	VGS = ±16 V, VDS = 0 V			±10	μΑ
Gate-source threshold Voltage	Vth	ID = -1.0 mA, VDS = -10.0 V	-1		-2.5	V
Drain-source On-state Resistance *1	RDS(on)1	ID = -7.0 A, VGS = -10 V		19	25	mΩ
	RDS(on)2	ID = -3.5 A, VGS = -4.5 V		28	45	
Forward transfer admittance *1	Yfs	ID = -7.0 A, VDS = -10 V	10			S
Input Capacitance	Ciss			2 700		
Output Capacitance	Coss	VDS = -10 V, VGS = 0 V, f = 1 MH;		190		pF
Reverse Transfer Capacitance	Crss			175		
Turn-on Delay Time *1,*2	td(on)	VDD = -25 V, VGS = 0 V to -10 V		18		ns
Rise Time *1,*2	tr	ID = -3.5 A		15		
Turn-off Delay Time *1,*2	td(off)	VDD = -25 V, VGS = -10 V to 0 V		230		ns
Fall Time *1,*2	tf	ID = -3.5 A		70		

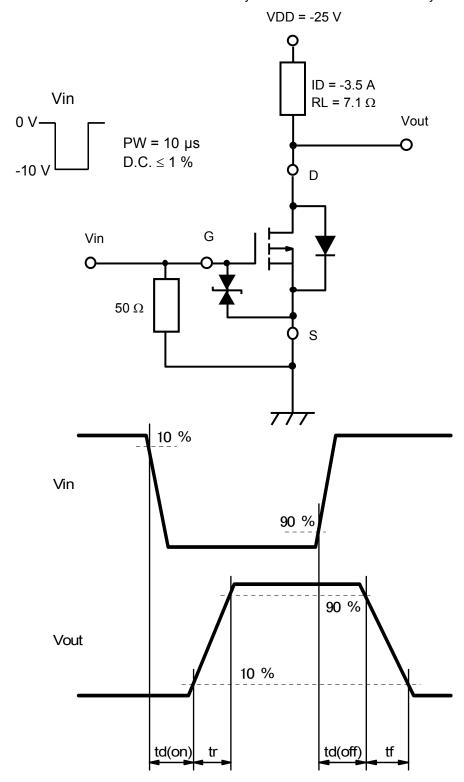
Note: 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

Established: 2007-11-08 : 2013-10-15 Revised

<sup>2. \*1</sup> Pulse test

<sup>\*2</sup> Measurement circuit for Turn-on Delay Time/Rise Time/Turn-off Delay Time/Fall Time

\*2 Measurement circuit for Turn-on Delay Time/Rise Time/Turn-off Delay Time/Fall Time



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## Technical Data (reference)

ID - VDS -2.5 -10.0 V -2 Drain Current ID (A) -1.5 -1 -0.5 2.0 V 0 -0.04 -0.06 -0.08 -0.1 0 -0.02 Drain-source Voltage VDS (V)

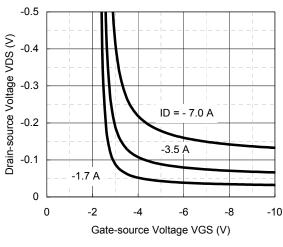
-3 Ta = 85 °C Ta = 85 °C -40 °C 0 -2.5 -1 -1.5 -2 -2.5

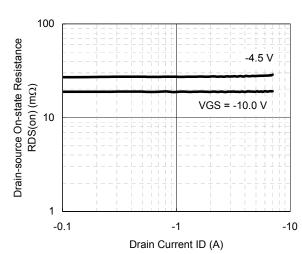
ID - VGS





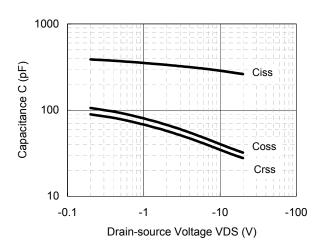
Gate-source voltage VGS (V)

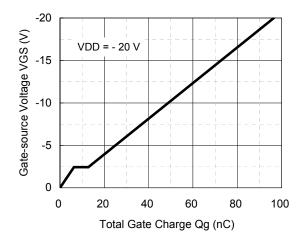




Capacitance - VDS

Dynamic Input/Output Characteristics

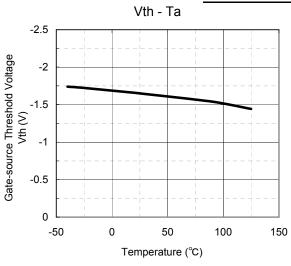


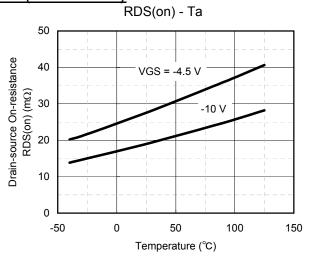


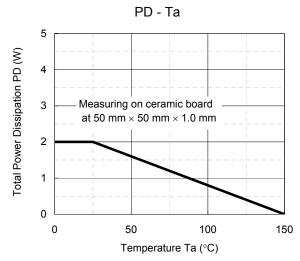
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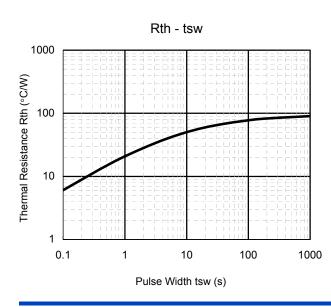
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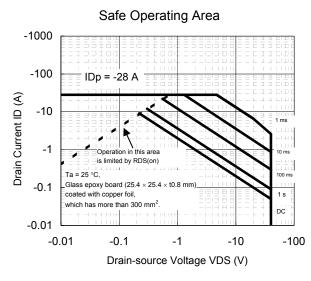
## Technical Data (reference)











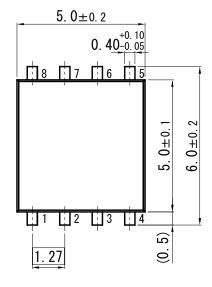
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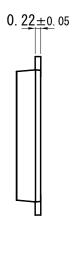
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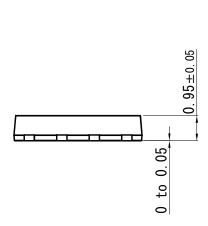
## MTM981400BBF

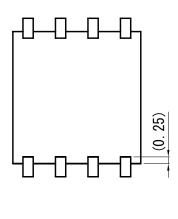
SO8-F1-B

Unit: mm

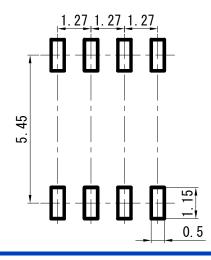








■ Land Pattern (Reference) (Unit: mm)



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